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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Christopher D.W. Jones

Serial No.: N/A

Filed: Herewith

For: INTERDIGITATED CAPACITORS AND METHOD OF  
MANUFACTURE THEREOF

Commissioner for Patents  
Washington, D. C. 20231

Sir:

I hereby certify that this correspondence, including the attachments listed, is being deposited with the United States Postal Service, Express Mail - Post Office to Addressee, Receipt No. <u>EL344526411US</u> , in an envelope addressed to Commissioner of Patents and Trademarks, Washington, D.C. 20231, on the date shown below.	
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INFORMATION DISCLOSURE STATEMENT

Pursuant to the duty of disclosure under 37 C.F.R. § 1.56, Applicant submits this statement. This submittal is made in accordance with 37 C.F.R. §§ 1.97 and 1.98 and § 609 of the Manual of Patent Examining Procedure. The patents, publications and other information herein are listed below and on the attached Form PTO-1449. Copies of the listed references are submitted herewith.

U.S. Patent No.

Inventor

Date

5,414,588

Barbee, Jr. et al.

May 9, 1995

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Applicant hereby expressly reserves the right to swear behind the effective dates of any of the above Patents and to question the relevance and materiality of the Patents and Publications listed herein, in whole, in part, or in combination, subsequent to filing this Information Disclosure Statement.

Respectfully submitted,

HITT GAINES & BOISBRUN, P.C.

A handwritten signature in dark ink, appearing to read "Charles W. Gaines", is written over a horizontal line.

Charles W. Gaines  
Registration No. 36,804

Date: 8/14/01

P.O. Box 832570  
Richardson, Texas 75083  
(972) 480-8800